NSN 5962-01-144-8987

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View Online at https://aerobasegroup.com/nsn/5962-01-144-8987

view Offilite at https://aerobasegroup.com/hist//0302-01-144-0307
Body Length:
Between 1.185 inches and 1.215 inches
Body Width:
Between 0.570 inches and 0.605 inches
Body Height:
0.145 inches
Maximum Power Dissipation Rating:
525.0 milliwatts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Anadigtester e/i fscm 88818
Features Provided:
Hermetically sealed and monolithic and positive outputs and electrostatic sensitive and erasable and low power and programmable and
programmed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 6.0 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
88818-a398a033t1021 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer
drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:

N/a

24 printed circuit

Unit Of Measure:

Shelf Life:

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Demilitarization:

Yes - demil/mli

Fiig:

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